

RJH60M5DPQ-A0

600 V - 37 A - IGBT Application: Inverter

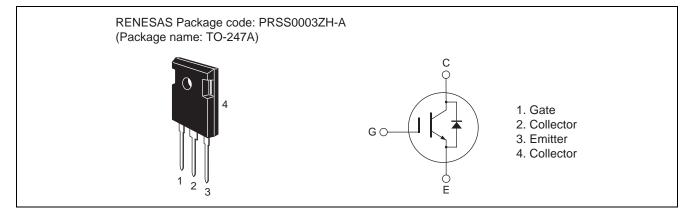
R07DS0536EJ0100 Rev.1.00 Sep 02, 2011

Features

- Short circuit withstand time (8 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.8$ V typ. (at $I_C = 37$ A, $V_{GE} = 15$ V, $Ta = 25^{\circ}C$)
- Built in fast recovery diode (100 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching

 $t_f = 80$ ns typ. (at $V_{CC} = 300$ V, $V_{GE} = 15$ V, $I_C = 37$ A, $Rg = 5 \Omega$, $Ta = 25^{\circ}C$, inductive load)

Outline



Absolute Maximum Ratings

				$(Ta = 25^{\circ}C)$
Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	600	V
Gate to emitter voltage		V _{GES}	±30	V
Collector current	Tc = 25°C	Ι _C	75	А
	Tc = 100°C	Ι _C	37	А
Collector peak current		ic(peak) Note1	150	А
Collector to emitter diode forward current		I _{DF}	30	А
Collector to emitter diode forward peak current		i _{DF} (peak) ^{Note1}	120	А
Collector dissipation		P _C ^{Note2}	200	W
Junction to case thermal resistance (IGBT)		θj-c ^{Note2}	0.63	°C/W
Junction to case thermal resistance (Diode)		θj-cd ^{Note2}	2.1	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. $PW \le 10 \ \mu s$, duty cycle $\le 1\%$

2. Value at Tc = 25°C



Electrical Characteristics

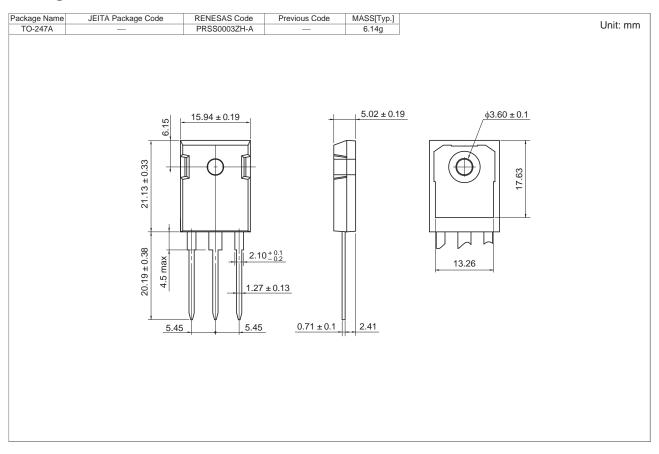
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Zero gate voltage collector current / Diode reverse current	I _{CES} / I _R	—	—	5	μA	$V_{CE} = 600 \text{ V}, \text{ V}_{GE} = 0$	
Gate to emitter leak current	I _{GES}	—	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, \text{ V}_{CE} = 0$	
Gate to emitter cutoff voltage	V _{GE(off)}	5	_	7	V	$V_{CE} = 10 \text{ V}, \text{ I}_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.8	2.3	V	$I_{C} = 37 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
	V _{CE(sat)}	_	2.2	—	V	I_{C} =75 A, V_{GE} = 15 V ^{Note3}	
Input capacitance	Cies	_	1900	—	pF	V _{CE} = 25 V	
Output capacitance	Coes	_	120	_	pF	V _{GE} = 0 f = 1 MHz	
Reverse transfer capacitance	Cres	_	60	_	pF		
Total gate charge	Qg	_	78	_	nC	V _{GE} = 15 V	
Gate to emitter charge	Qge	_	12	_	nC	V _{CE} = 300 V	
Gate to collector charge	Qgc		36	—	nC	I _C = 37 A	
Switching time	t _{d(on)}		50	—	ns	$V_{CC} = 300 \text{ V}, \text{ V}_{GE} = 15 \text{ V}$	
	tr	_	35	—	ns	I _C = 37 A	
	t _{d(off)}		130	_	ns	$Rg = 5 \Omega$	
	t _f	_	80	_	ns	Inductive load	
Short circuit withstand time	t _{sc}	6	8	_	μS	$\label{eq:constraint} \begin{array}{l} Tc = 100 \ ^{\circ}C \\ V_{CC} \leq 360 \ V, \ V_{GE} = 15 \ V \end{array}$	
				_			
FRD Forward voltage	VF	—	1.4	1.9	V	$I_F = 30 \text{ A}^{\text{Note3}}$	
FRD reverse recovery time	trr	_	100	_	ns	I _F = 30 A	

FRD reverse recovery time	t _{rr}		100	ns	I _F = 30 A
					di _F /dt = 100 A/µs

Notes: 3. Pulse test.



Package Dimension



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH60M5DPQ-A0-T0	240 pcs	Box (Tube)



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